

# Silicon Dual Diode

## **BYV44-400**

400V/30A

# DATASHEET

OEM – Philips

Source: Philips Databook 1999

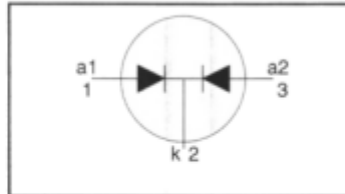
## Dual rectifier diodes ultrafast

## BYV44 series

### FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- High thermal cycling performance
- Low thermal resistance

### SYMBOL



### QUICK REFERENCE DATA

$$V_R = 300 \text{ V} / 400 \text{ V} / 500 \text{ V}$$

$$V_F \leq 1.12 \text{ V}$$

$$I_{O(AV)} = 30 \text{ A}$$

$$t_{rr} \leq 60 \text{ ns}$$

### GENERAL DESCRIPTION

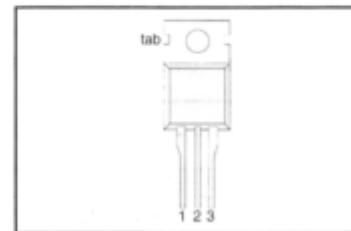
Dual, common cathode, ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV44 series is supplied in the conventional leaded SOT78 (TO220AB) package.

### PINNING

PIN	DESCRIPTION
1	anode 1
2	cathode
3	anode 2
tab	cathode

### SOT78 (TO220AB)



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
				-300	-400	-500	
$V_{RRM}$	Peak repetitive reverse voltage	<b>BYV44</b> $T_{me} \leq 136^\circ\text{C}$	-	300	400	500	V
$V_{RWM}$	Crest working reverse voltage		-	300	400	500	V
$V_R$	Continuous reverse voltage		-	300	400	500	V
$I_{O(AV)}$	Average rectified output current (both diodes conducting) <sup>1</sup>	square wave; $\delta = 0.5$ ; $T_{mb} \leq 94^\circ\text{C}$	-	30			A
$I_{FRM}$	Repetitive peak forward current per diode	$t = 25 \mu\text{s}$ ; $\delta = 0.5$ ; $T_{mb} \leq 94^\circ\text{C}$	-	30			A
$I_{FSM}$	Non-repetitive peak forward current per diode.	$t = 10 \text{ ms}$	-	150			A
		$t = 8.3 \text{ ms}$	-	160			A
$T_{stg}$	Storage temperature	$V_{RRM(max)}$	-40	150			$^\circ\text{C}$
$T_J$	Operating junction temperature		-	150			$^\circ\text{C}$

### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th(j-hs)}$	Thermal resistance junction to heatsink	per diode	-	-	2.4	K/W
$R_{th(j-a)}$	Thermal resistance junction to ambient	both diodes conducting	-	-	1.4	K/W
		in free air.	-	60	-	K/W

<sup>1</sup> Neglecting switching and reverse current losses.

For output currents in excess of 20 A, the cathode connection should be made to the metal mounting tab.

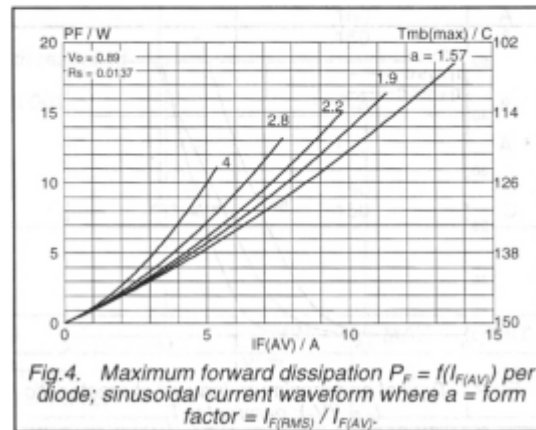
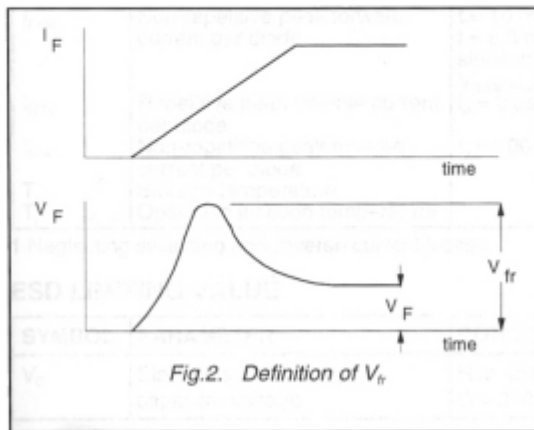
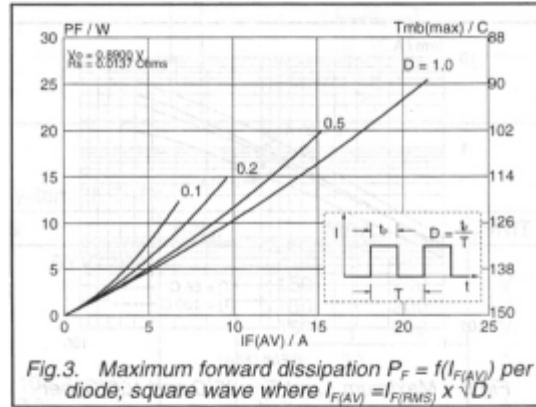
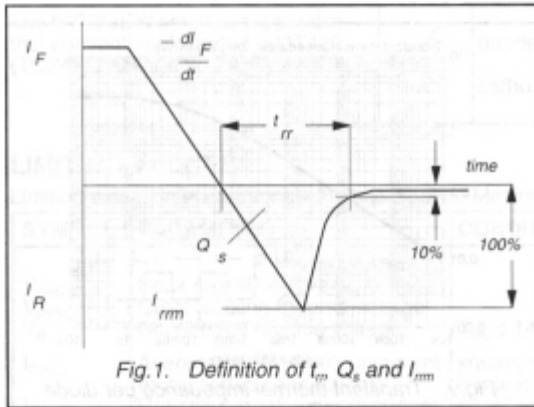
Dual rectifier diodes  
ultrafast

BYV44 series

**ELECTRICAL CHARACTERISTICS**

characteristics are per diode at  $T_j = 25\text{ }^\circ\text{C}$  unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_F$	Forward voltage	$I_F = 15\text{ A}; T_j = 150\text{ }^\circ\text{C}$	-	0.95	1.12	V
		$I_F = 15\text{ A}$	-	1.08	1.25	V
		$I_F = 30\text{ A}$	-	1.15	1.36	V
$I_R$	Reverse current	$V_R = V_{RRM}; T_j = 100\text{ }^\circ\text{C}$	-	10	50	$\mu\text{A}$
		$V_R = V_{RRM}; T_j = 100\text{ }^\circ\text{C}$	-	0.3	0.8	mA
$Q_s$	Reverse recovery charge	$I_F = 2\text{ A to } V_R \geq 30\text{ V};$ $di_F/dt = 20\text{ A}/\mu\text{s}$	-	40	60	nC
$t_{rr}$	Reverse recovery time	$I_F = 1\text{ A to } V_R \geq 30\text{ V};$ $di_F/dt = 100\text{ A}/\mu\text{s}$	-	50	60	ns
$I_{rrm}$	Peak reverse recovery current	$I_F = 10\text{ A to } V_R \geq 30\text{ V};$ $di_F/dt = 50\text{ A}/\mu\text{s}; T_j = 100\text{ }^\circ\text{C}$	-	4.2	5.2	A
$V_{fr}$	Forward recovery voltage	$I_F = 10\text{ A}; di_F/dt = 10\text{ A}/\mu\text{s}$	-	2.5	-	V



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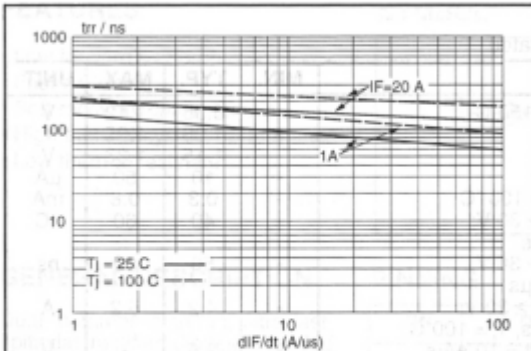


Fig.5. Maximum  $t_{rr}$  at  $T_j = 25\text{ C}$  and  $100\text{ C}$ ; per diode

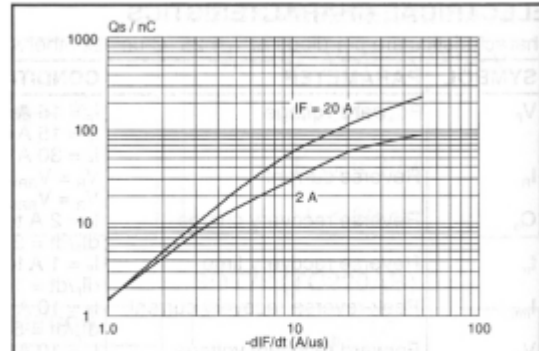


Fig.8. Maximum  $Q_s$  at  $T_j = 25\text{ C}$ ; per diode

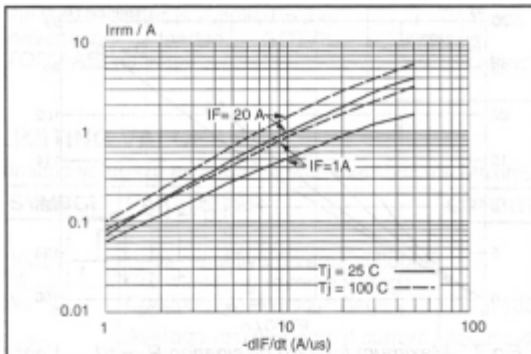


Fig.6. Maximum  $I_{rrm}$  at  $T_j = 25\text{ C}$  and  $100\text{ C}$ ; per diode

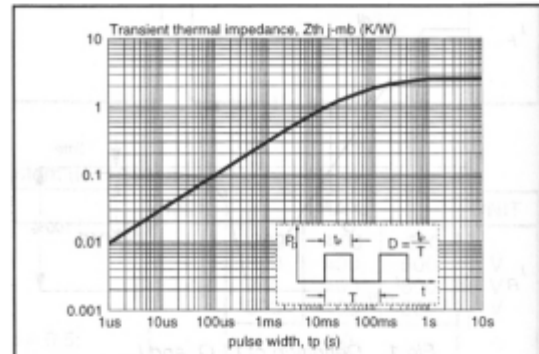


Fig.9. Transient thermal impedance per diode  $Z_{th(j-mb)} = f(t_p)$

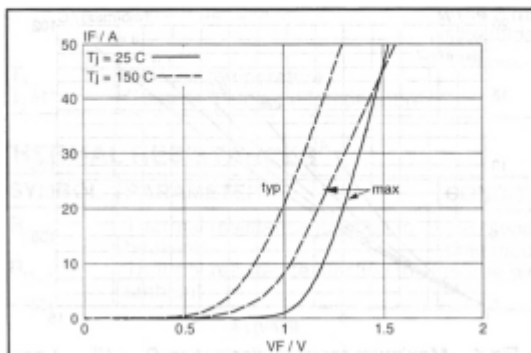


Fig.7. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$